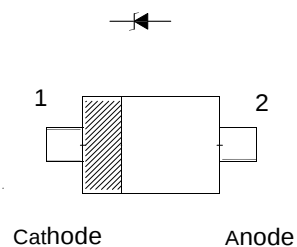


SOD-323 Plastic-Encapsulate Zener Diode

FEATURES

- Planar die construction
- 200mW power dissipation on ceramic PBC
- General purpose, medium current
- Ideally suited for automated assembly processes
- Available in lead free version
- Tolerance approximately $\pm 5\%$



Maximum Ratings ($T_a=25^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Value	Unit
Forward Voltage (Note 2) @ $I_F = 10\text{mA}$	V_F	0.9	V
Power Dissipation(Note 1)	P_D	200	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~+150	$^\circ\text{C}$

SOD-323 Plastic-Encapsulate Zener Diode

Electrical Characteristics(T_a = 25°C unless otherwise specified)

TYPE	Zener Voltage Range (Note 2)				Maximum Zener Impedance (Note 3)			Maximum Reverse Current (Note 2)		Typical Temperature Coefficient @I _{ZTC} mV/°C		Test Current I _{ZTC}
	V _Z @I _{ZT}			I _{ZT}	Z _{ZT} @I _{ZT}	Z _{ZK} @I _{ZK}	I _{ZK}	I _R	V _R	Min	Max	mA
Nom(V)	Min(V)	Max(V)	(mA)	Ω		(mA)	μA	V	Min	Max	mA	
AS2V4A201T	2.4	2.20	2.60	5	100	600	1.0	50	1.0	-3.5	0	5
AS2V7A201T	2.7	2.5	2.9	5	100	600	1.0	20	1.0	-3.5	0	5
AS3V0A201T	3.0	2.8	3.2	5	95	600	1.0	10	1.0	-3.5	0	5
AS3V3A201T	3.3	3.1	3.5	5	95	600	1.0	5	1.0	-3.5	0	5
AS3V6A201T	3.6	3.4	3.8	5	90	600	1.0	5	1.0	-3.5	0	5
AS3V9A201T	3.9	3.7	4.1	5	90	600	1.0	3	1.0	-3.5	0	5
AS4V3A201T	4.3	4.0	4.6	5	90	600	1.0	3	1.0	-3.5	0	5
AS4V7A201T	4.7	4.4	5.0	5	80	500	1.0	3	2.0	-3.5	0.2	5
AS5V1A201T	5.1	4.8	5.4	5	60	480	1.0	2	2.0	-2.7	1.2	5
AS5V6A201T	5.6	5.2	6.0	5	40	400	1.0	1	2.0	-2	2.5	5
AS6V2A201T	6.2	5.8	6.6	5	10	150	1.0	3	4.0	0.4	3.7	5
AS6V8A201T	6.8	6.4	7.2	5	15	80	1.0	2	4.0	1.2	4.5	5
AS7V5A201T	7.5	7.0	7.9	5	15	80	1.0	1	5.0	2.5	5.3	5
AS8V2A201T	8.2	7.7	8.7	5	15	80	1.0	0.7	5.0	3.2	6.2	5
AS9V1A201T	9.1	8.5	9.6	5	15	100	1.0	0.5	6.0	3.8	7.0	5
AS10VA201T	10	9.4	10.6	5	20	150	1.0	0.2	7.0	4.5	8.0	5
AS11VA201T	11	10.4	11.6	5	20	150	1.0	0.1	8.0	5.4	9.0	5
AS12VA201T	12	11.4	12.7	5	25	150	1.0	0.1	8.0	6.0	10.0	5
AS13VA201T	13	12.4	14.1	5	30	170	1.0	0.1	8.0	7.0	11.0	5
AS15VA201T	15	13.8	15.6	5	30	200	1.0	0.1	10.5	9.2	13	5
AS16VA201T	16	15.3	17.1	5	40	200	1.0	0.1	11.2	10.4	14	5
AS18VA201T	18	16.8	19.1	5	45	225	1.0	0.1	12.6	12.4	16	5
AS20VA201T	20	18.8	21.2	5	55	225	1.0	0.1	14.0	14.4	18.0	5
AS22VA201T	22	20.8	23.3	5	55	250	1.0	0.1	15.4	16.4	20.0	5
AS24VA201T	24	22.8	25.6	5	70	250	1.0	0.1	16.8	18.4	22.0	5
AS27VA201T	27	25.1	28.9	2	80	300	0.5	0.1	18.9	21.4	25.3	2
AS30VA201T	30	28.0	32.0	2	80	300	0.5	0.1	21.0	24.4	29.4	2
AS33VA201T	33	31.0	35.0	2	80	325	0.5	0.1	23.1	27.4	33.4	2
AS36VA201T	36	34.0	38.0	2	90	350	0.5	0.1	25.2	30.4	37.4	2
AS39VA201T	39	37.0	41.0	2	130	350	0.5	0.1	27.3	33.4	41.2	2

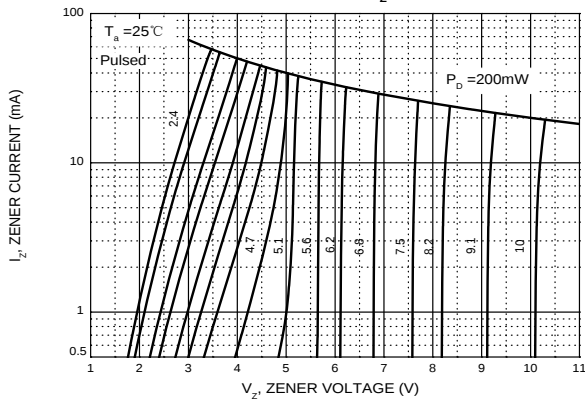
Notes: 1. Device mounted on ceramic PCB: 7.6mm x 9.4mm x 0.87mm with pad areas 25mm² ·

2. Short duration test pulse used to minimize self-heating effect.

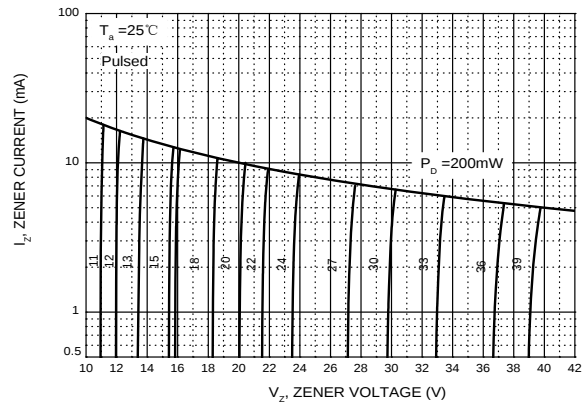
3. f = 1kHz.

SOD-323 Plastic-Encapsulate Zener Diode

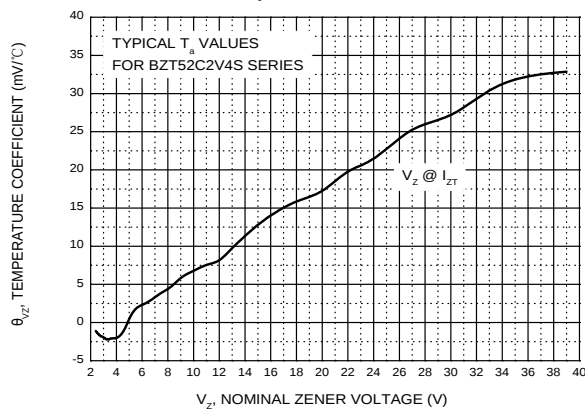
Zener Characteristics (V_z Up to 10 V)



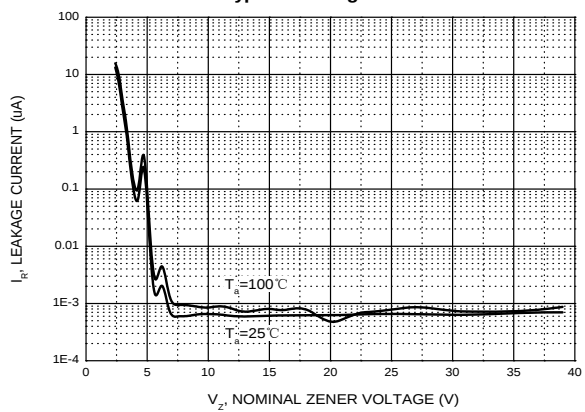
Zener Characteristics (11 V to 39 V)



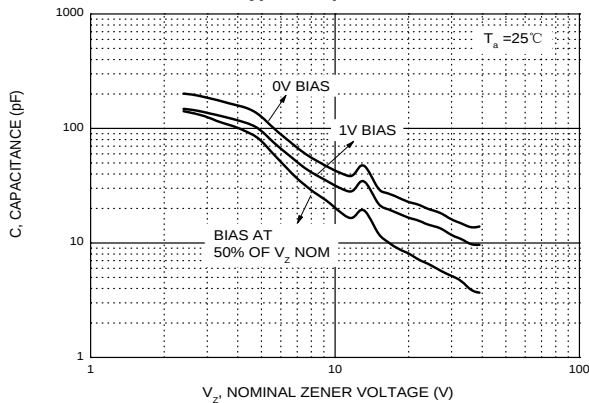
Temperature Coefficients



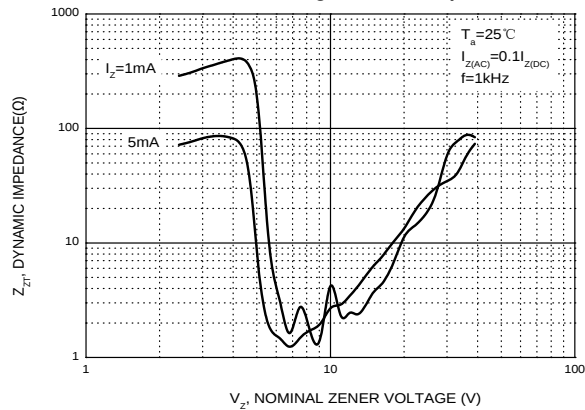
Typical Leakage Current



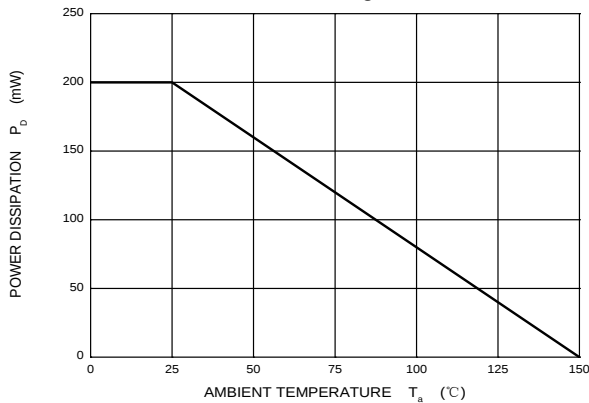
Typical Capacitance



Effect of Zener Voltage on Zener Impedance



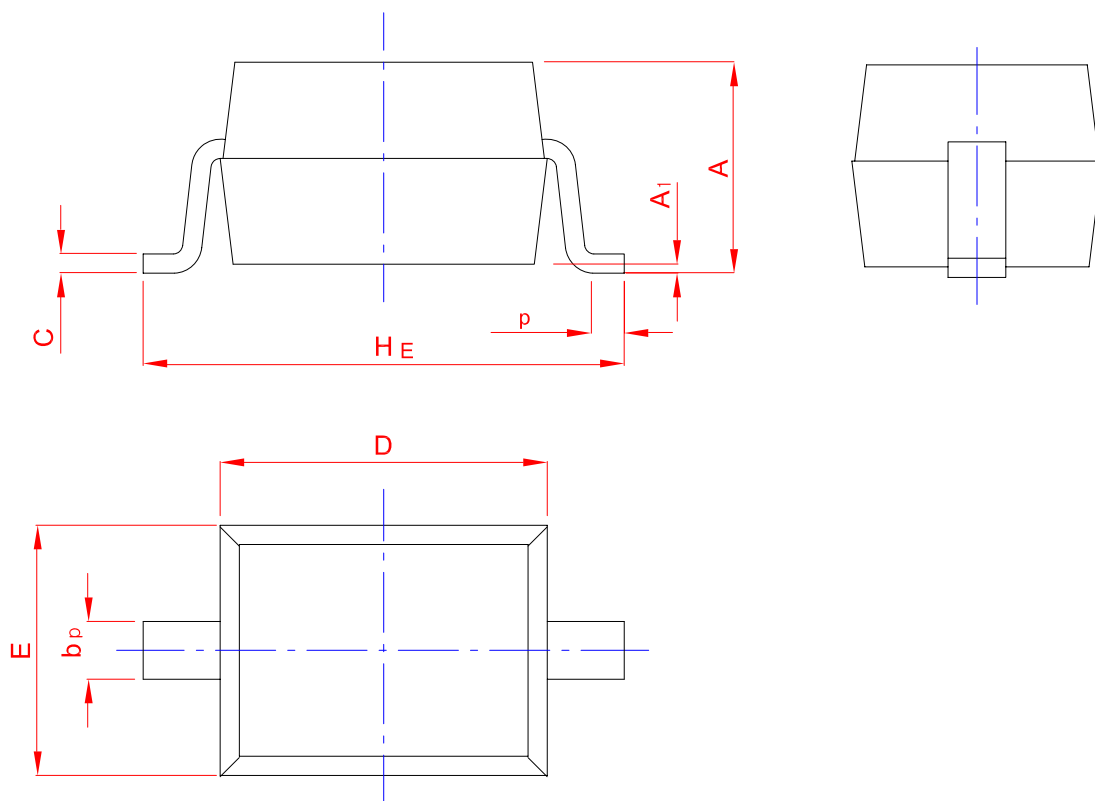
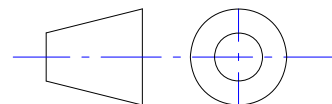
Power Derating Curve



SOD-323 Plastic-Encapsulate Zener Diode

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads



UNIT	A	b _p	C	D	E	H _E	A ₁	L _p
mm	1.20 0.80	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30	0.10 0.01	0.50 0.20